AUK Semiconductor

STA3350F

PNP Silicon Transistor

Applications

- Power amplifier application
- High current switching application

Features

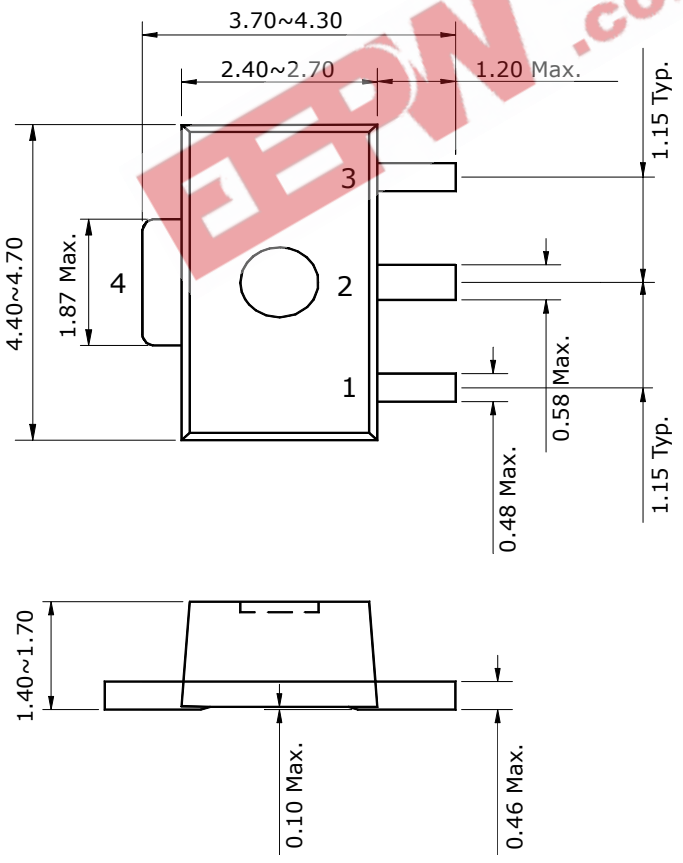
- Low saturation voltage: $V_{CE(sat)}$=-0.15V Typ. @ I_C=-1A, I_B=-50mA
- Large collector current capacity: I_C=-3A
- Small and compact SMD type package
- Complementary pair with STC4350F

Ordering Information

Type NO.	Marking	Package Code
STA3350F	HW7	SOT-89

Outline Dimensions

unit : mm



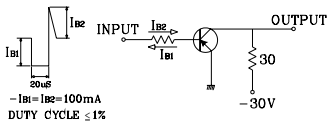
PIN Connections
1. Base
2,4. Collector
3. Emitter

Absolute Maximum Ratings [Ta=25℃]

Characteristic	Symbol	Rating	Unit
Collector-base voltage	V_{CBO}	-50	V
Collector-emitter voltage	V_{CEO}	-50	V
Emitter-base voltage	V_{EBO}	-6	V
Collector current	I_C	-3	A
Collector Power dissipation	P_C	0.5	W
	P_C※	1	W
Junction temperature	T_J	150	°C
Storage temperature range	T_{stg}	-55~150	°C

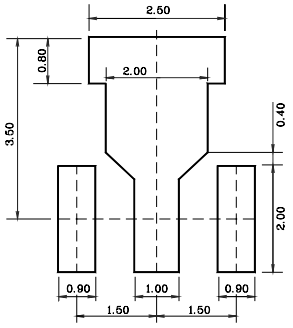
※ Device mounted on ceramic substrate (250mm^2 x 0.8t)

Electrical Characteristics [Ta=25℃]

Characteristic		Symbol	Test Condition	Min.	Typ.	Max.	Unit
Collector-emitter breakdown voltage		BV_{CEO}	I_C=-1mA, I_B=0	-50	-	-	V
Collector cut-off current		I_{CBO}	V_{CB}=-50V, I_E=0	-	-	-1	μA
Emitter cut-off current		I_{EBO}	V_{EB}=-6V, I_C=0	-	-	-1	μA
DC current gain		h_{FE}	V_{CE}=-2V, I_C=-0.5A*	120	-	240	
		h_{FE}	V_{CE}=-2V, I_C=-2A*	40	-	-	
Collector-emitter saturation voltage		$V_{CE(sat)}$	I_C=-1A, I_B=-0.05A*	-	-	-0.35	V
Base-emitter saturation voltage		$V_{BE(sat)}$	I_C=-2A, I_B=-0.1A*	-	-0.97	-1.2	V
Transition frequency		f_T	V_{CE}=-10V, I_C=-0.05A	-	250	-	MHz
Collector output capacitance		C_{ob}	V_{CB}=-10V, I_E=0, f=1MHz	-	28	-	pF
Switching Time	Turn-on Time	t_{on}		-	100	-	ns
	Storage Time	t_{stg}		-	300	-	
	Fall Time	t_f		-	50	-	

*: Pulse test : t_P≤300μs, Duty cycle≤2%

※ Recommend PCB solder land [Unit: mm]



Electrical Characteristic Curves

Fig. 1 P_C - T_a

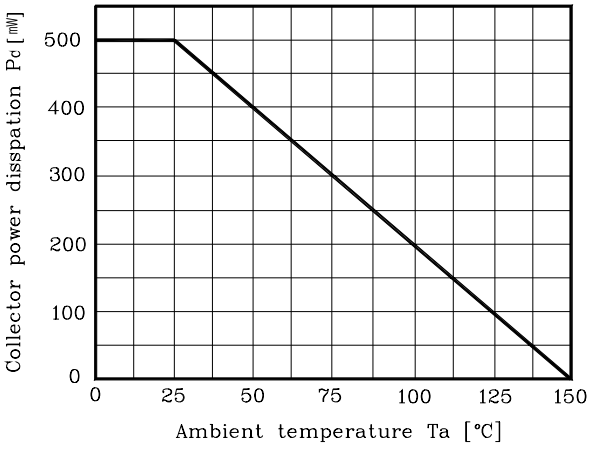


Fig. 2 I_C - V_{BE}

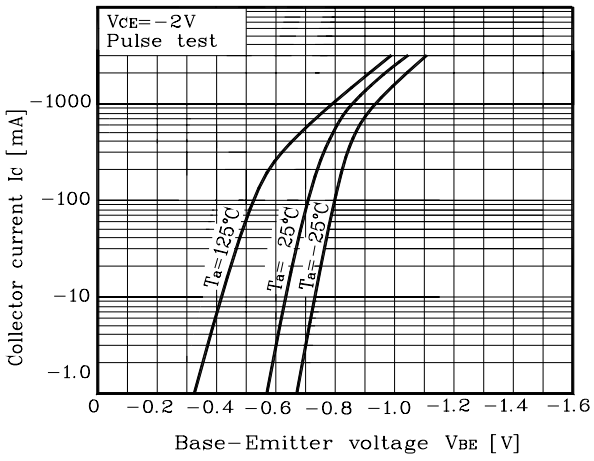


Fig. 3 I_C - V_{CE}

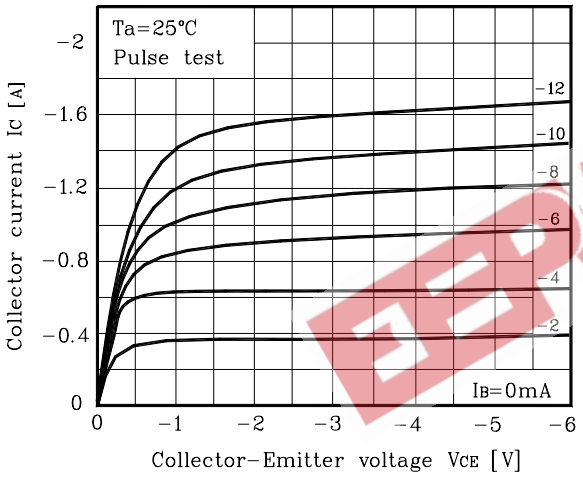


Fig. 4 h_{FE} - I_C

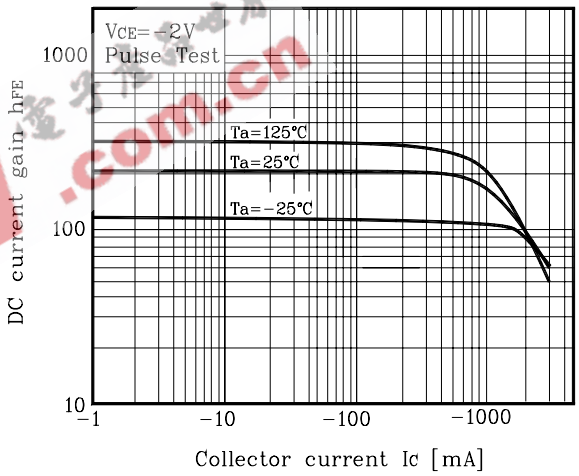


Fig. 5 $V_{CE(sat)}$ - I_C

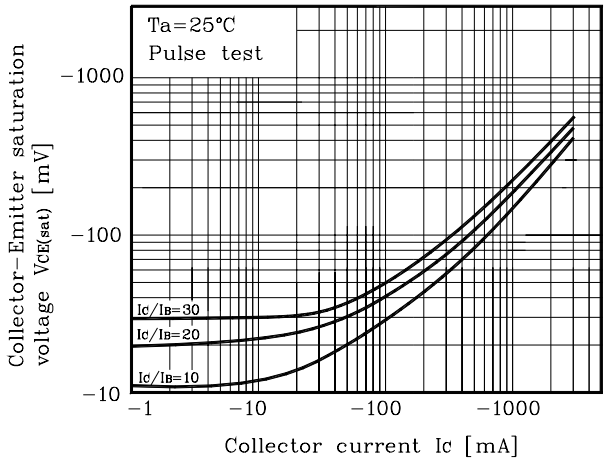
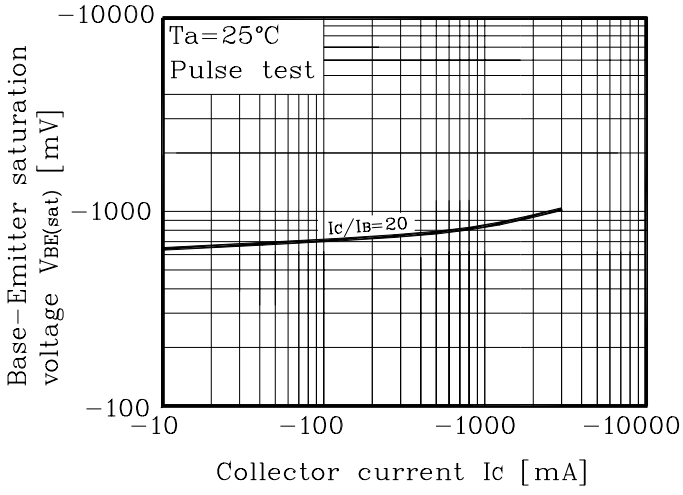


Fig. 6 $V_{BE(sat)}$ - I_C



Electrical Characteristic Curves

Fig. 7 C_{Ob} - V_{CB}

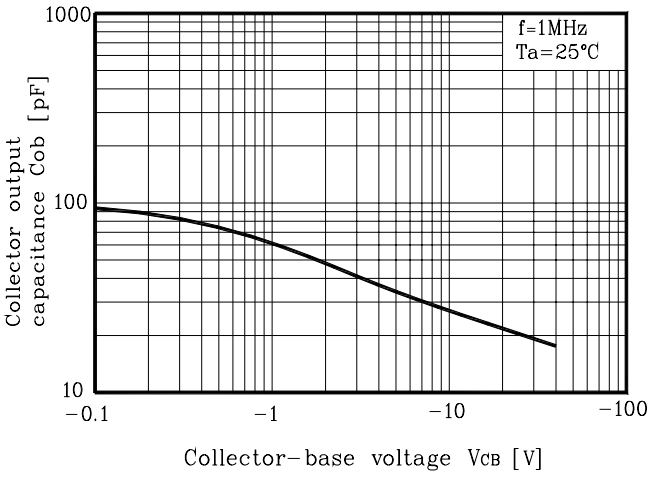


Fig. 8 Safe Operating Area